Correction to the Article

“INVESTIGATION OF THE SIGNAL SHAPE GIVEN BY n - p AND p - n TYPE SEMICONDUCTOR DETECTORS WITH PULSE SHAPE DISCRIMINATION“

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Owing to an unfortunate error of translation lines 1 to 6 of the last paragraph on page 408 of the article are to be replaced by the following:

“The measurements were carried out on three different detectors. Two of them were surface barrier detectors, prepared from n type base material, the first one with 200 mm² surface and 800 Ohm.cm resistivity, the second one with 16 mm² surface and 2000 Ohm.cm resistivity. The third detector was a diffused junction one prepared from p type base material, with 7 mm² surface and 10000 Ohm.cm resistivity.”